NSN 5961-00-186-1245

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-186-1245 **Inclosure Material:** Glass and metal **Overall Length:** 0.850 inches **Overall Diameter:** 0.570 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.180 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.2 regulator voltage **Current Rating Per Characteristic:** 200.00 milliamperes reverse surge current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release3482 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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